



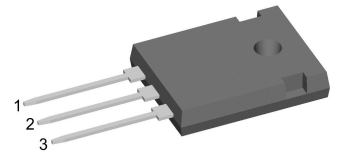
# FRED

$V_{RRM} = 600\text{ V}$   
 $I_{FAV} = 2 \times 30\text{ A}$   
 $t_{rr} = 35\text{ ns}$

## Fast Recovery Epitaxial Diode Common Cathode

### Part number

**DSEK60-06A**



Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

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Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					600	V
$V_{RRM}$	max. repetitive reverse blocking voltage					600	V
$I_R$	reverse current, drain current	$V_R = 600\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		100	$\mu\text{A}$
		$V_R = 480\text{ V}$		$T_{VJ} = 125^\circ\text{C}$		7	mA
$V_F$	forward voltage drop	$I_F = 37\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		1.52	V
		$I_F = 74\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		1.71	V
		$I_F = 37\text{ A}$		$T_{VJ} = 150^\circ\text{C}$		1.36	V
		$I_F = 74\text{ A}$		$T_{VJ} = 150^\circ\text{C}$		1.64	V
$I_{FAV}$	average forward current	$T_C = 110^\circ\text{C}$	rectangular	$T_{VJ} = 150^\circ\text{C}$		30	A
$V_{FO}$	threshold voltage	} for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		1.10	V
$r_F$	slope resistance					8.5	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					0.8	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.25		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		155	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		300	A
$C_J$	junction capacitance	$V_R = 600\text{ V}$ $f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		22	pF
$I_{RM}$	max. reverse recovery current	} $I_F = 37\text{ A}; V_R = 350\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		5.5	A
				$T_{VJ} = 100^\circ\text{C}$		9	A
$t_{rr}$	reverse recovery time	} $-di_F/dt = 200\text{ A}/\mu\text{s}$		$T_{VJ} = 25^\circ\text{C}$		80	ns
				$T_{VJ} = 100^\circ\text{C}$		150	ns



Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			70	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		150	°C
<b>Weight</b>				6		g
$M_D$	mounting torque		0.8		1.2	Nm
$F_C$	mounting force with clip		20		120	N

**Product Marking**



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEK60-06A	DSEK60-06A	Tube	30	471534

**Equivalent Circuits for Simulation**

*\* on die level*

$T_{VJ} = 150^{\circ}C$

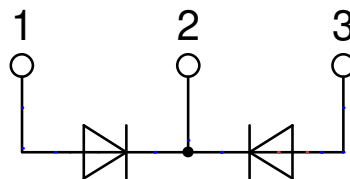


**Fast Diode**

$V_{0\ max}$	threshold voltage	1.1	V
$R_{0\ max}$	slope resistance *	6	mΩ



**Outlines TO-247**





**Fast Diode**

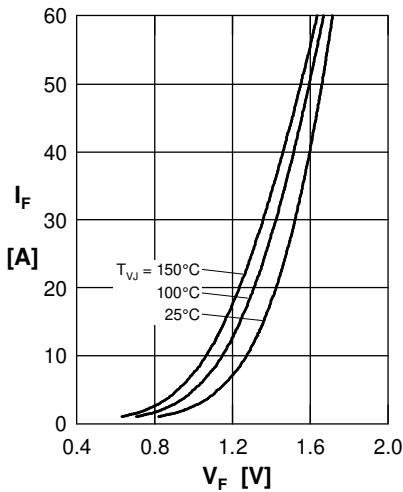


Fig. 1 Forward current  $I_F$  versus max. forward voltage drop  $V_F$

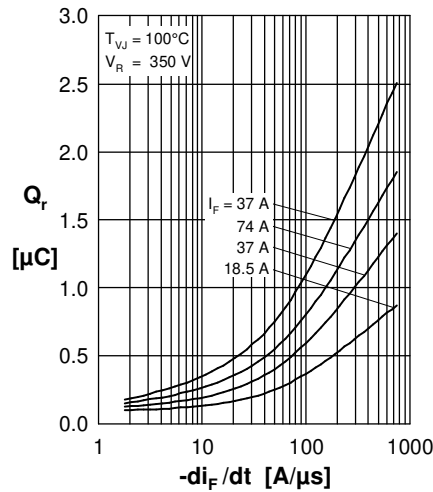


Fig. 2 Typ. reverse recov. charge  $Q_r$  versus  $-di_F/dt$

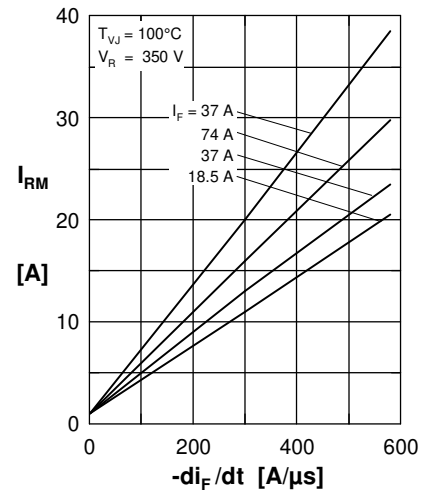


Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$

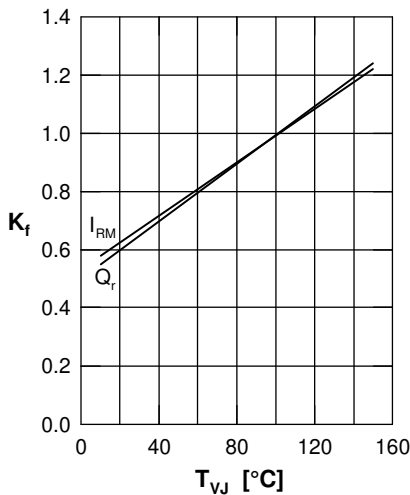


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

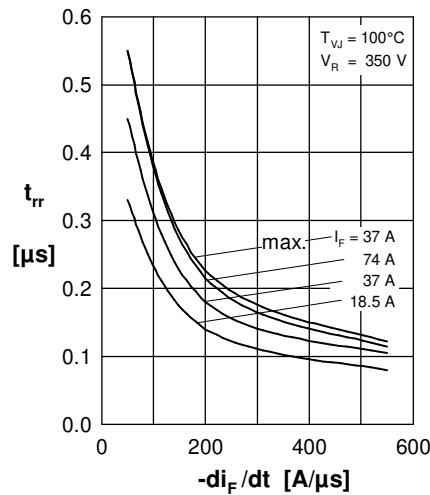


Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$

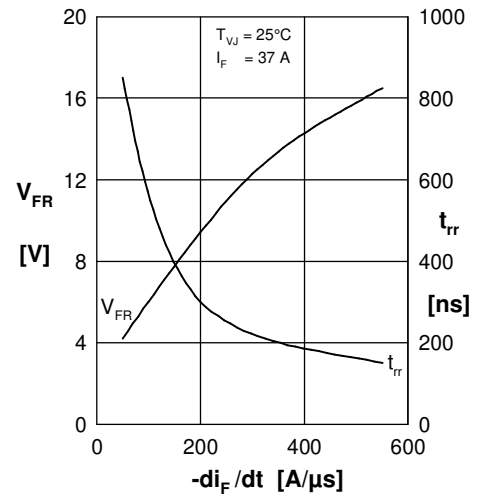


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

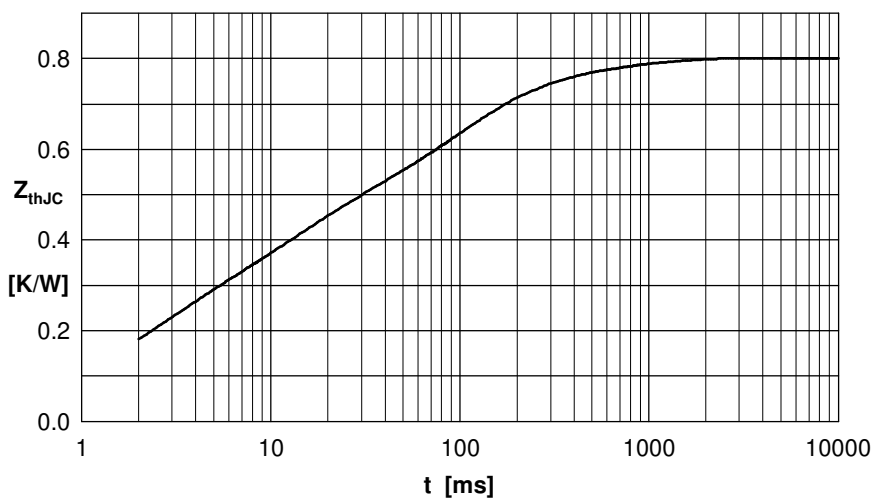


Fig. 7 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.200	0.0018
2	0.220	0.0100
3	0.080	0.5000
4	0.300	0.0900